

TOSHIBA Transistor Silicon NPN Epitaxial Planar Type

MT6L11FS

VHF~UHF Band Low-Noise Amplifier Applications

Two devices are incorporated in a fine-pitch, small-mold package (6 pins): fS6.

- Superior noise characteristics
- Superior performance in buffer and oscillator applications.

Mounted Devices

	Q1/Q2
Corresponding three-pin products:TESM(fSM) mold products	MT3S11T (MT3S11FS)

Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector- base voltage	VCBO	13	V
Collector- emitter voltage	VCEO	6	V
Emitter- base voltage	VEBO	1	V
Collector current	IC	40	mA
Base current	IB	10	mA
Collector power dissipation	PC(Note 1)	100	mW
		110 (Note 2)	
Junction temperature	Tj	125	°C
Storage temperature range	Tstg	−55~125	°C

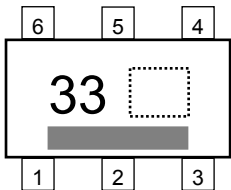
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

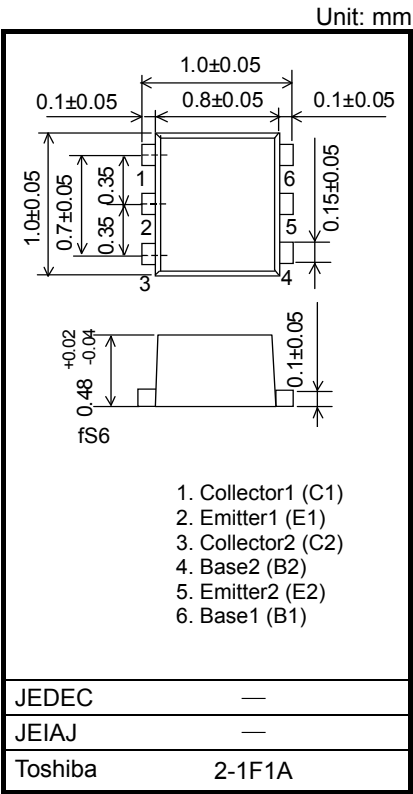
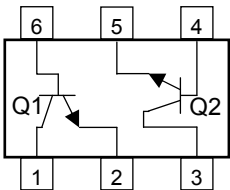
Note 1: 10 mm² × 1.0 mm (t), mounted on a glass-epoxy printed circuit board.

Note 2: During two-element operation

Marking (top view)



Pin Assignment (top view)



Weight: 0.001g (typ.)

Electrical Characteristics Q1/Q2 (Ta = 25°C)

Characteristic	Symbol	Condition	Min	Typ.	Max	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 5\text{ V}, I_E = 0$	—	—	0.1	μA
Emitter cutoff current	I_{EBO}	$V_{EB} = 1\text{ V}, I_C = 0$	—	—	1	μA
DC current gain	h_{FE}	$V_{CE} = 1\text{ V}, I_C = 5\text{ mA}$	100	—	160	
Reverse transfer capacitance	C_{re} (Note)	$V_{CB} = 1\text{ V}, I_E = 0, f = 1\text{ MHz}$	—	0.65	0.9	pF
Transition frequency	f_T	$V_{CE} = 1\text{ V}, I_C = 5\text{ mA}$	4	6	—	GHz
Insertion gain	$ S_{21e} ^2$ (1)	$V_{CE} = 1\text{ V}, I_C = 5\text{ mA}, f = 2\text{ GHz}$	—	3.5	—	dB
	$ S_{21e} ^2$ (2)	$V_{CE} = 3\text{ V}, I_C = 20\text{ mA}, f = 2\text{ GHz}$	4	6.5	—	
Noise figure	NF	$V_{CE} = 1\text{ V}, I_C = 5\text{ mA}, f = 2\text{ GHz}$	—	2.4	3.2	dB

Note: C_{re} is measured with a three-terminal method using a capacitance bridge.

Caution

This device is sensitive to electrostatic discharge. Ensure that tools and equipment are sufficiently grounded before handling. When handling individual devices (which are not yet mounted on a circuit board), ensure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

RESTRICTIONS ON PRODUCT USE

20070701-EN GENERAL

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